

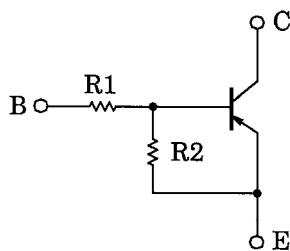
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2607, RN2608, RN2609

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

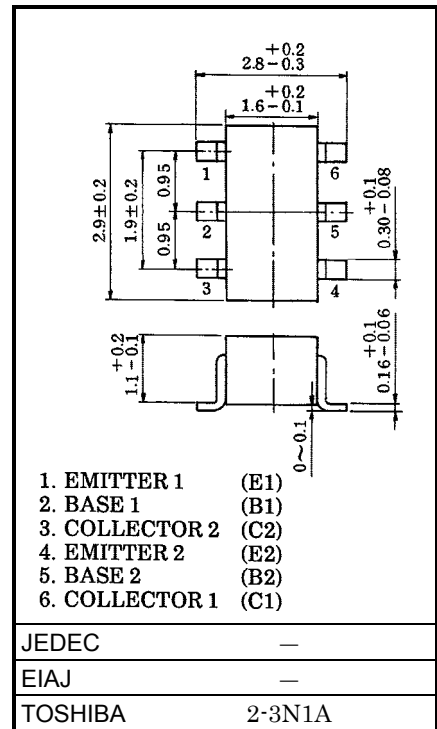
- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1607~RN1609

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2607	10	47
RN2608	22	47
RN2609	47	22

Unit in mm



1. EMITTER 1 (E1)
2. BASE 1 (B1)
3. COLLECTOR 2 (C2)
4. EMITTER 2 (E2)
5. BASE 2 (B2)
6. COLLECTOR 1 (C1)

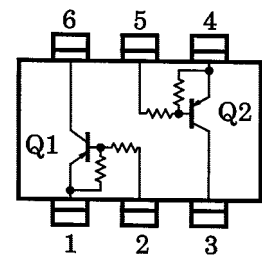
Weight: 0.015g

Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Collector-base voltage	RN2607~RN2609	V_{CB0}	-50	V
Collector-emitter voltage		V_{CE0}	-50	V
Emitter-base voltage	RN2607	V_{EB0}	-6	V
	RN2608		-7	
	RN2609		-15	
Collector current	I_C	-100	mA	
Collector power dissipation	P_C^*	300	mW	
Junction temperature	T_j	150	°C	
Storage temperature range	T_{stg}	-55~150	°C	

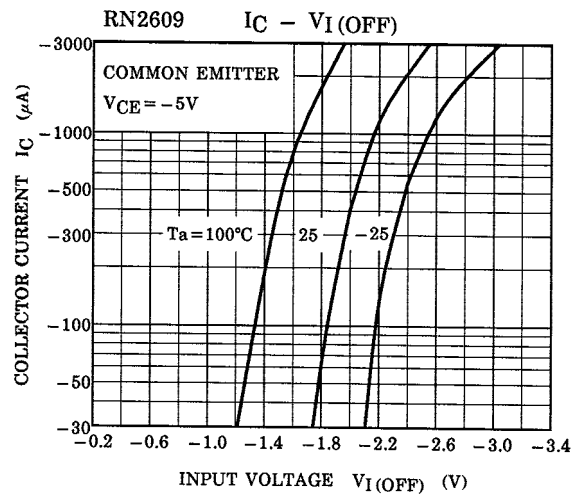
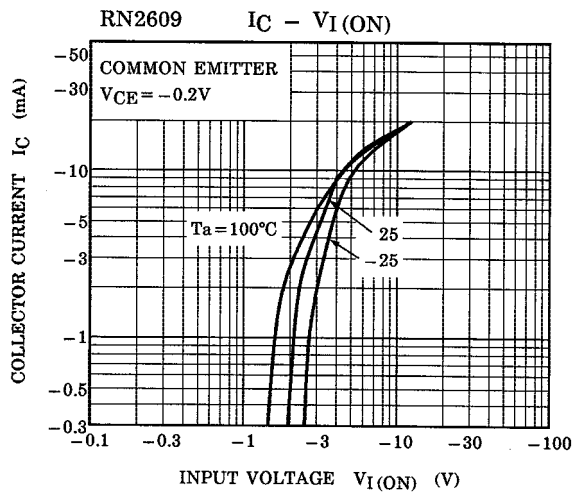
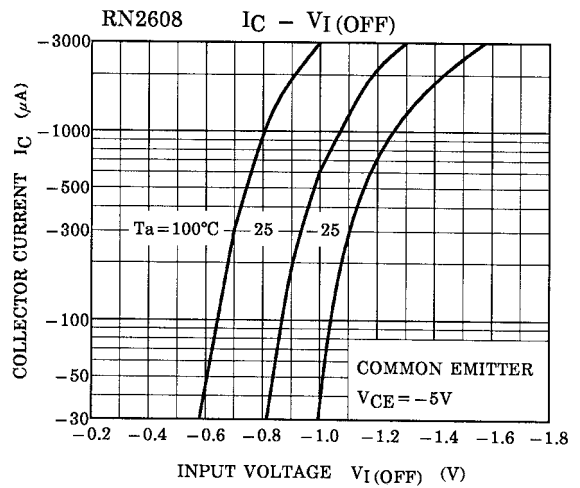
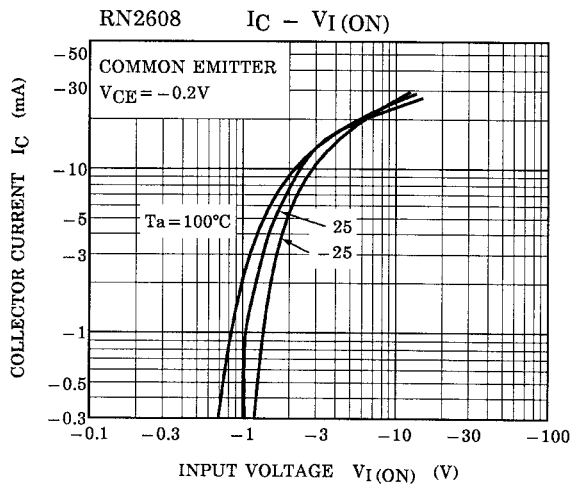
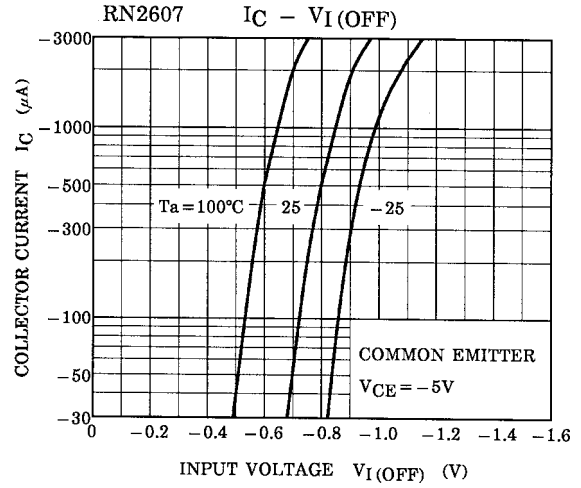
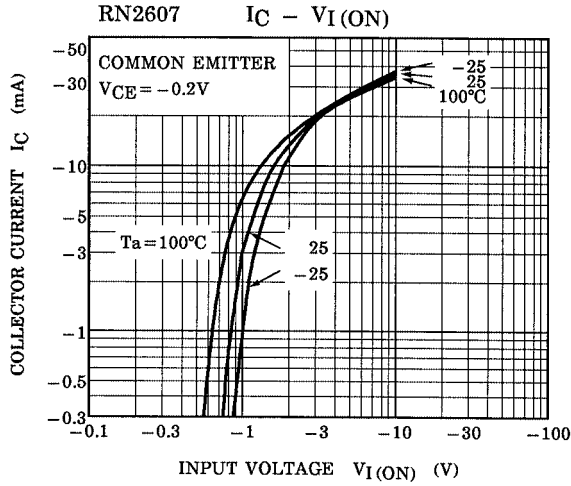
* Total rating



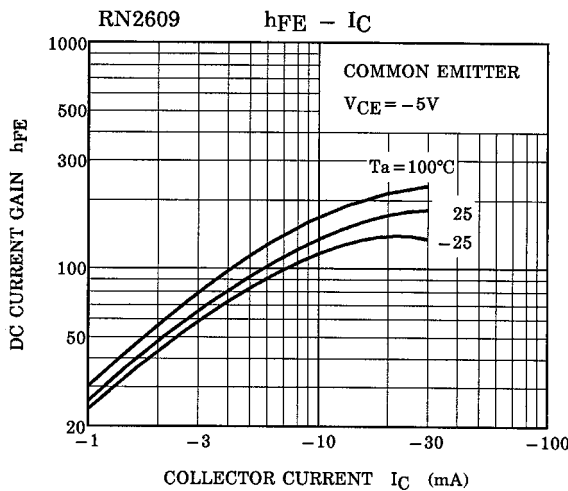
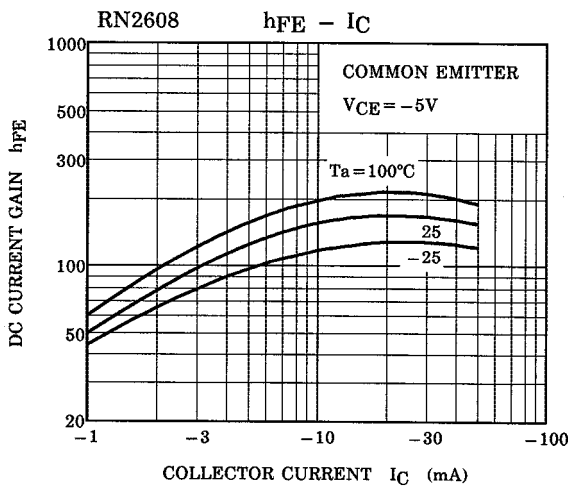
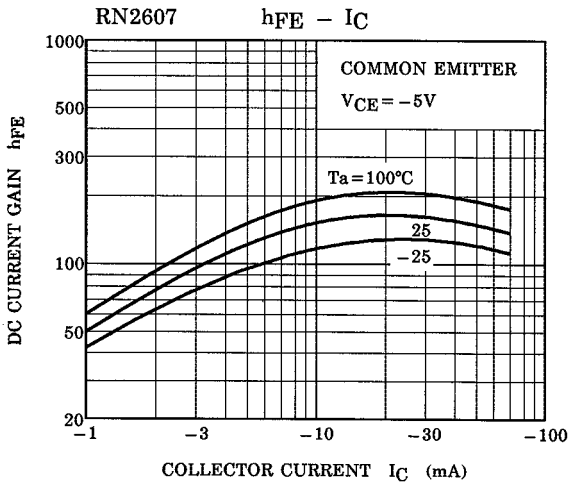
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

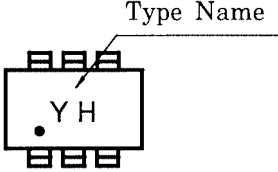
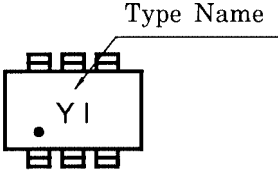
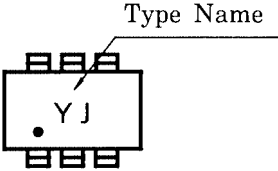
Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2607~RN2609	I_{CBO}	—	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
		I_{CEO}	—	$V_{CE} = -50V, I_B = 0$	—	—	-500	nA
Emitter cut-off current	RN2607	I_{EBO}	—	$V_{EB} = -6V, I_C = 0$	-0.081	—	-0.15	mA
	RN2608		—	$V_{EB} = -7V, I_C = 0$	-0.078	—	-0.145	
	RN2609		—	$V_{EB} = -15V, I_C = 0$	-0.167	—	-0.311	
DC current gain	RN2607	h_{FE}	—	$V_{CE} = -5V, I_C = -10mA$	80	—	—	—
	RN2608		—		80	—	—	
	RN2609		—		70	—	—	
Collector-emitter saturation voltage	RN2607~RN2609	$V_{CE(sat)}$	—	$I_C = -5mA, I_B = -0.25mA$	—	-0.1	-0.3	V
Input voltage (ON)	RN2607	$V_{I(ON)}$	—	$V_{CE} = -0.2V, I_C = -5mA$	-0.7	—	-1.8	V
	RN2608		—		-1.0	—	-2.6	
	RN2609		—		-2.2	—	-5.8	
Input voltage (OFF)	RN2607	$V_{I(OFF)}$	—	$V_{CE} = -5V, I_C = -0.1mA$	-0.5	—	-1.0	V
	RN2608		—		-0.6	—	-1.16	
	RN2609		—		-1.5	—	-2.6	
Translation frequency	RN2607~RN2609	f_T	—	$V_{CE} = -10V, I_C = -5mA$	—	200	—	MHz
Collector output capacitance	RN2607~RN2609	C_{ob}	—	$V_{CB} = -10V, I_E = 0$ $f = 1MHz$	—	3	6	pF
Input resistor	RN2607	R1	—	—	7	10	13	kΩ
	RN2608		—		15.4	22	28.6	
	RN2609		—		32.9	47	61.1	
Resistor ratio	RN2607	R1/R2	—	—	0.191	0.213	0.232	—
	RN2608		—		0.421	0.468	0.515	
	RN2609		—		1.92	2.14	2.35	

(Q1, Q2 Common)



(Q1, Q2 Common)



Type Name	Marking
RN2607	 <p>The diagram shows a rectangular component with four pins on each of the top and bottom edges. Inside the rectangle, the characters 'YH' are printed, with a small dot to the left of the 'Y'. A line labeled 'Type Name' points to the top-right corner of the component.</p>
RN2608	 <p>The diagram shows a rectangular component with four pins on each of the top and bottom edges. Inside the rectangle, the characters 'YI' are printed, with a small dot to the left of the 'Y'. A line labeled 'Type Name' points to the top-right corner of the component.</p>
RN2609	 <p>The diagram shows a rectangular component with four pins on each of the top and bottom edges. Inside the rectangle, the characters 'YJ' are printed, with a small dot to the left of the 'Y'. A line labeled 'Type Name' points to the top-right corner of the component.</p>

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.